

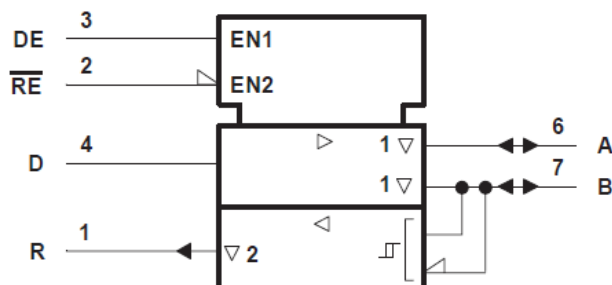
SNx5ALS176, SN75ALS176A, and SN75ALS176B Differential Bus Transceivers

1 Features

- Meet or exceed the requirements of TIA/EIA-422-B, TIA/EIA-485-A¹ and ITU recommendations V.11 and X.27
- Operate at data rates up to 35 Mbaud
- Four skew limits available:
 - SN65ALS176: 15 ns
 - SN75ALS176: 10 ns
 - SN75ALS176A: 7.5 ns
 - SN75ALS176B: 5 ns
- Designed for multipoint transmission on long bus lines in noisy environments
- Low supply-current requirements: 30 mA max
- Wide positive and negative input/output bus-voltage ranges
- Thermal shutdown protection
- Driver positive and negative current limiting
- Receiver input hysteresis
- Glitch-free power-up and power-down protection
- Receiver open-circuit fail-safe design

2 Description

The SN65ALS176 and SN75ALS176 series differential bus transceivers are designed for bidirectional data communication on multipoint bus transmission lines. The devices are designed for balanced transmission lines and meet TIA/EIA-422-B, TIA/EIA-485-A, and ITU Recommendations V.11 and X.27.



A. This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Logic Symbol

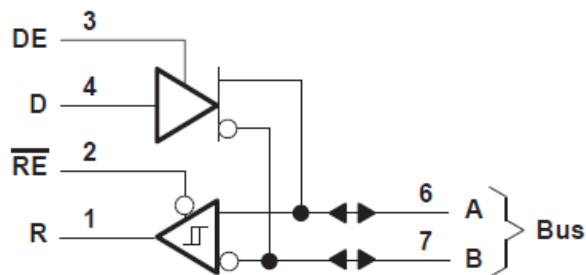
The SN65ALS176 and SN75ALS176 series combine a 3-state, differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, that can be connected together externally to function as a direction control. The driver differential outputs and the receiver differential inputs are connected internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus when the driver is disabled or $V_{CC} = 0$. This port features wide positive and negative common-mode voltage ranges, making the device suitable for party-line applications.

The SN65ALS176 is characterized for operation from -40°C to 85°C . The SN75ALS176 series is characterized for operation from 0°C to 70°C .

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
SNx5ALS176	D (SOIC)	4.9 mm x 3.91 mm
	P (PDIP)	9.81 mm x 6.35 mm
SN75ALS176A	D (SOIC)	4.9 mm x 3.91 mm
	P (PDIP)	9.81 mm x 6.35 mm
SN75ALS176B	D (SOIC)	4.9 mm x 3.91 mm
	P (PDIP)	9.81 mm x 6.35 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)

¹ These devices meet or exceed the requirements of TIA/EIA-485-A, except for the Generator Contention Test (para. 3.4.2) and the Generator Current Limit (para. 3.4.3). The applied test voltage ranges are -6 V to 8 V for the SN75ALS176, SN75ALS176A, and SN75ALS176B and -4 V to 8 V for the SN65ALS180.



Table of Contents

1 Features	1	6 Parameter Measurement Information	11
2 Description	1	7 Detailed Description	14
3 Revision History	2	7.1 Functional Block Diagram.....	14
4 Pin Configuration and Functions	3	7.2 Device Functional Modes.....	14
5 Specifications	4	8 Application and Implementation	15
5.1 Absolute Maximum Ratings	4	8.1 Application Information.....	15
5.2 Recommended Operating Conditions.....	4	8.2 Typical Application.....	15
5.3 Thermal Information.....	4	9 Device and Documentation Support	16
5.4 Electrical Characteristics - Driver.....	5	9.1 Documentation Support.....	16
5.5 Switching Characteristics - Driver.....	5	9.2 Receiving Notification of Documentation Updates....	16
5.6 Switching Characteristics - Driver.....	6	9.3 Support Resources.....	16
5.7 Symbol Equivalents.....	6	9.4 Trademarks.....	16
5.8 Electrical Characteristics - Receiver.....	7	9.5 Electrostatic Discharge Caution.....	16
5.9 Switching Characteristics - Receiver.....	7	9.6 Glossary.....	16
5.10 Switching Characteristics - Receiver.....	8	10 Mechanical, Packaging, and Orderable Information	16
5.11 Typical Characteristics.....	9		

3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision H (June 2000) to Revision I (January 2023)	Page
• Changed the document to the latest TI format.....	1
• Deleted the Package thermal impedance from the <i>Absolute Maximum Ratings</i>	4
• Added the <i>Thermal Information</i> table.....	4
• Changed the <i>Typical Characteristics</i> graphs.....	9

4 Pin Configuration and Functions

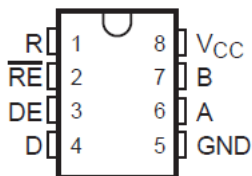


Figure 4-1. D or P Package (Top View)

Table 4-1. Pin Functions

NO	Name	Type	Description
1	R	O	Receive data output
2	$\overline{RE}$	I	Receiver enable, active low
3	DE	i	Driver enable, active high
4	D	I	Driver data input
5	GND	GND	Local device ground
6	A	I/O	Driver output or receiver input (complementary to B)
7	B	I/O	Driver output or receiver input (complementary to A)
8	V_{CC}	SUPPLY	4.75-V to 5.25-V supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾		7	V
	Voltage range at any bus terminal	-7	12	V
V _I	Enable input voltage		5.5	V
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.

5.2 Recommended Operating Conditions

(unless otherwise noted)

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		4.75	5	5.25	V
V _I or V _{IC}	Input voltage at any bus terminal (separately or common mode)				12 -7	V
V _{IH}	High-level input voltage	D, DE, and RE	2			V
V _{IL}	Low-level input voltage	D, DE, and RE			0.8	V
V _{ID}	Differential input voltage ⁽¹⁾				±12	V
I _{OH}	High-level output current	Driver			-60	mA
		Receiver			-400	µA
I _{OL}	Low-level output current	Driver			60	mA
		Receiver			8	
T _A	Operating free-air temperature	SN65ALS176	-40		85	°C
		SN75ALS176 series	0		70	

- (1) Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

5.3 Thermal Information

THERMAL METRIC ⁽¹⁾		P (PDIP)	D (SOIC) SN65 Devices	D (SOIC) SN75 Devices	UNIT
		8-Pins	8-Pins	8-Pin	
R _{θJA}	Junction-to-ambient thermal resistance	65.7	116.7	110	°C/W
R _{θJC(top)}	Junction-to-case thermal resistance	54.7	56.3	44.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	42.1	63.4	53.5	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	23	8.8	4.8	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	41.7	62.6	52.7	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.4 Electrical Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP ⁽²⁾	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = –18 mA				–1.5	V
V _O	Output voltage	I _O = 0		0		6	V
V _{OD1}	Differential output voltage	I _O = 0		1.5		6	V
V _{OD2}	Differential output voltage	R _L = 100 Ω	See Figure 6-1	$\frac{1}{2} V_{OD1}$ or 2 ⁽³⁾			V
		R _L = 54 Ω	See Figure 6-1	1.5	2.5	5	V
V _{OD3}	Differential output voltage	V _{test} = –7 V to 12 V,	See Figure 6-2	1.5		5	V
Δ V _{OD}	Change in magnitude of differential output voltage ⁽⁴⁾	R _L = 54 Ω or 100 Ω	See Figure 6-1			±0.2	V
V _{OC}	Common-mode output voltage	R _L = 54 Ω or 100 Ω	See Figure 6-1			3 –1	V
Δ V _{OC}	Change in magnitude of common-mode output voltage ⁽⁴⁾	R _L = 54 Ω or 100 Ω	See Figure 6-1			±0.2	V
I _O	Output current	Outputs disabled ⁽⁶⁾	V _O = 12 V			1	mA
			V _O = –7 V			–0.8	
I _{IH}	High-level input current	V _I = 2.4 V				20	μA
I _{IL}	Low-level input current	V _I = 0.4 V				–400	μA
I _{OS}	Short-circuit output current ⁽⁵⁾	V _O = –4 V	SN65ALS176			–250	mA
		V _O = –6 V	SN75ALS176			–250	
		V _O = 0				–150	
		V _O = V _{CC}				250	
		V _O = 8 V				250	
I _{CC}	Supply current	No load	Outputs enabled		23	30	mA
			Outputs disabled		19	26	

- (1) The power-off measurement in TIA/EIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.
- (2) All typical values are at V_{CC} = 5 V and T_A = 25°C.
- (3) The minimum V_{OD2} with a 100-Ω load is either 1/2 V_{OD1} or 2 V, whichever is greater.
- (4) Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of VOD and VOC, respectively, that occur when the input is changed from one logic state to the other.
- (5) Duration of the short circuit should not exceed one second for this test.
- (6) This applies for power on and power off. Refer to TIA/EIA-485-A for exact conditions. The TIA/EIA-422-B limit does not apply for a combined driver and receiver terminal.

5.5 Switching Characteristics - Driver

SN65ALS176

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP ⁽¹⁾	MAX	UNIT
t _{d(OD)}	Differential output delay time	R _L = 54 Ω	C _L = 50 pF,	See Figure 6-3			15	ns
t _{sk(p)}	Pulse skew ⁽²⁾	R _L = 54 Ω	C _L = 50 pF,	See Figure 6-3		0	2	ns
t _{sk(lim)}	Pulse skew ⁽³⁾	R _L = 54 Ω	C _L = 50 pF,	See Figure 6-3			15	ns
t _{t(OD)}	Differential output transition time	R _L = 54 Ω	C _L = 50 pF,	See Figure 6-3		8		ns
t _{PZH}	Output enable time to high level	R _L = 110 Ω	C _L = 50 pF,	See Figure 6-4			80	ns
t _{PZL}	Output enable time to low level	R _L = 110 Ω	C _L = 50 pF,	See Figure 6-5			30	ns
t _{PHZ}	Output disable time from high level	R _L = 110 Ω	C _L = 50 pF,	See Figure 6-4			50	ns
t _{PLZ}	Output disable time from low level	R _L = 110 Ω	C _L = 50 pF,	See Figure 6-5			30	ns

- (1) All typical values are at V_{CC} = 5 V, T_A = 25°C.

- (2) Pulse skew is defined as the $|t_{PLH} - t_{PHL}|$ of each channel of the same device.
 (3) Skew limit is the maximum difference in propagation delay times between any two channels of any two devices.

5.6 Switching Characteristics - Driver

SN75ALS176, SN75ALS176A, SN75ALS176B

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MIN	TYP ⁽¹⁾	MAX	UNIT
$t_{d(OD)}$	Differential output delay time	'ALS176	$R_L = 54\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-3	3	8	13	ns
		'ALS176A				4	7	11.5	
		'ALS176B				5	8	10	
$t_{sk(p)}$	Pulse skew ⁽²⁾		$R_L = 54\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-3		0	2	ns
$t_{sk(lim)}$	Pulse skew ⁽³⁾	'ALS176	$R_L = 54\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-3			10	ns
		'ALS176A						7.5	
		'ALS176B						5	
$t_{i(OD)}$	Differential output transition time		$R_L = 54\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-3		8		ns
t_{PZH}	Output enable time to high level		$R_L = 110\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-4		23	50	ns
t_{PZL}	Output enable time to low level		$R_L = 110\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-5		14	20	ns
t_{PHZ}	Output disable time from high level		$R_L = 110\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-4		20	35	ns
t_{PLZ}	Output disable time from low level		$R_L = 110\ \Omega$	$C_L = 50\ \text{pF}$	See Figure 6-5		8	17	ns

- (1) All typical values are at $V_{CC} = 5\ \text{V}$, $T_A = 25^\circ\text{C}$.
 (2) Pulse skew is defined as the $|t_{PLH} - t_{PHL}|$ of each channel of the same device.
 (3) Skew limit is the maximum difference in propagation delay times between any two channels of any two devices.

5.7 Symbol Equivalents

DATA-SHEET PARAMETER	TIA/EIA-422-B	TIA/EIA-485-A
V_O	V_{oa}, V_{ob}	V_{oa}, V_{ob}
$ V_{OD1} $	V_o	V_o
$ V_{OD2} $	$V_t(R_L = 100\ \Omega)$	$V_t(R_L = 54\ \Omega)$
$ V_{OD3} $	None	V_t (test termination measurement 2)
$\Delta V_{OD} $	$ V_t - V_t $	$ V_t - V_t $
V_{OC}	$ V_{os} $	$ V_{os} $
$\Delta V_{OC} $	$ V_{os} - V_{os} $	$ V_{os} - V_{os} $
I_{OS}	$ I_{sa} , I_{sb} $	None
I_O	$ I_{xa} , I_{xb} $	I_{ia}, I_{ib}

5.8 Electrical Characteristics - Receiver

over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	V _O = 2.7 V,	I _O = –0.4 mA			0.2	V
V _{IT–}	Negative-going input threshold voltage	V _O = 0.5 V,	I _O = 8 mA	–0.2 ⁽²⁾			V
V _{hys}	Hysteresis voltage (V _{IT+} – V _{IT–})				60		mV
V _{IK}	Enable-input clamp voltage	I _I = –18 mA				–1.5	V
V _{OH}	High-level output voltage	V _{ID} = 200 mV, See Figure 6-6	I _{OH} = –400 mA,	2.7			V
V _{OL}	Low-level output voltage	V _{ID} = –200 mV, See Figure 6	I _{OL} = 8 mA,			0.45	V
I _{OZ}	High-impedance-state output current	V _O = 0.4 V to 2.4 V				±20	μA
V _I	Line input current	Other input = 0 V ⁽³⁾	V _I = 12 V			1	mA
			V _I = –7 V			–0.8	
I _{IH}	High-level-enable input current	V _{IH} = 2.7 V				20	μA
I _{IL}	Low-level-enable input current	V _{IL} = 0.4 V				–100	μA
r _I	Input resistance			12	20		kΩ
I _{OS}	Short-circuit output current	V _{ID} = 200 mV,	V _O = 0	–15		–85	mA
I _{CC}	Supply current	No load	Outputs enabled		23	30	mA
			Outputs disabled		19	26	

(1) All typical values are at V_{CC} = 5 V, T_A = 25°C.

(2) The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

(3) This applies for power on and power off. Refer to TIA/EIA-485-A for exact conditions.

5.9 Switching Characteristics - Receiver

SN65ALS176

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
t _{pd}	Propagation time	V _{ID} = –1.5 V to 1.5 V, See Figure 6-7	C _L = 15 pF,			25	ns
t _{sk(p)}	Pulse skew ⁽²⁾	V _{ID} = –1.5 V to 1.5 V, See Figure 6-7	C _L = 15 pF,		0	2	ns
t _{sk(lim)}	Pulse skew ⁽³⁾	R _L = 54 Ω See Figure 6-3	C _L = 50 pF,			15	ns
t _{PZH}	Output enable time to high level	C _L = 15 pF,	See Figure 6-8		11	18	ns
t _{PZL}	Output enable time to low level	C _L = 15 pF,	See Figure 6-8		11	18	ns
t _{PHZ}	Output disable time from high level	C _L = 15 pF,	See Figure 6-8			50	ns
t _{PLZ}	Output disable time from low level	C _L = 15 pF,	See Figure 6-8			30	ns

(1) All typical values are at V_{CC} = 5 V, T_A = 25°C.

(2) Pulse skew is defined as the |t_{PLH} – t_{PHL}| of each channel of the same device.

(3) Skew limit is the maximum difference in propagation delay times between any two channels of any two devices.

5.10 Switching Characteristics - Receiver

SN75ALS176, SN75ALS176A, SN75ALS176B

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
t_{pd}	Propagation time	'ALS176	$V_{ID} = -1.5\text{ V to }1.5\text{ V}$, See Figure 6-7	$C_L = 15\text{ pF}$,	9	14	19	ns
		'ALS176A			10.5	14	18	
		'ALS176B			11.5	13	16.5	
$t_{sk(p)}$	Pulse skew ⁽²⁾		$V_{ID} = -1.5\text{ V to }1.5\text{ V}$, See Figure 6-7	$C_L = 15\text{ pF}$,		0	2	ns
$t_{sk(lim)}$	Pulse skew ⁽³⁾	'ALS176	$R_L = 54\ \Omega$ See Figure 6-3	$C_L = 50\text{ pF}$,			10	ns
		'ALS176A					7.5	
		'ALS176B					5	
t_{PZH}	Output enable time to high level		$C_L = 15\text{ pF}$,	See Figure 6-8		7	14	ns
t_{PZL}	Output enable time to low level		$C_L = 15\text{ pF}$,	See Figure 6-8		20	35	ns
t_{PHZ}	Output disable time from high level		$C_L = 15\text{ pF}$,	See Figure 6-8		20	35	ns
t_{PLZ}	Output disable time from low level		$C_L = 15\text{ pF}$,	See Figure 6-8		8	17	ns

(1) All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

(2) Pulse skew is defined as the $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

(3) Skew limit is the maximum difference in propagation delay times between any two channels of any two devices.

5.11 Typical Characteristics

Operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied.

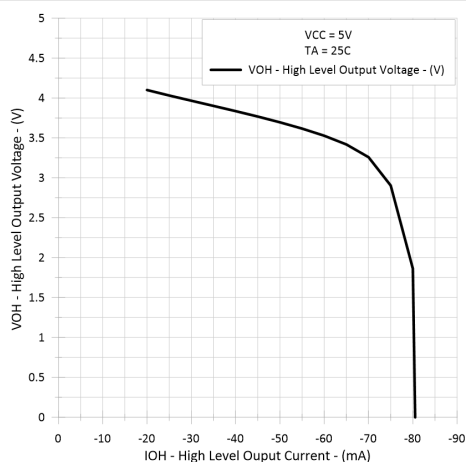


Figure 5-1. Driver High-Level Output Voltage vs High-Level Output Current

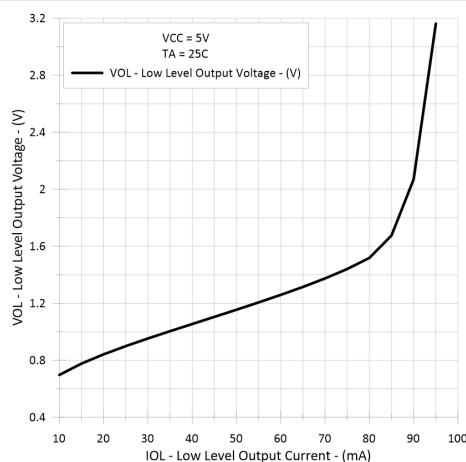


Figure 5-2. Driver Low-Level Output Voltage vs Low-Level Output Current

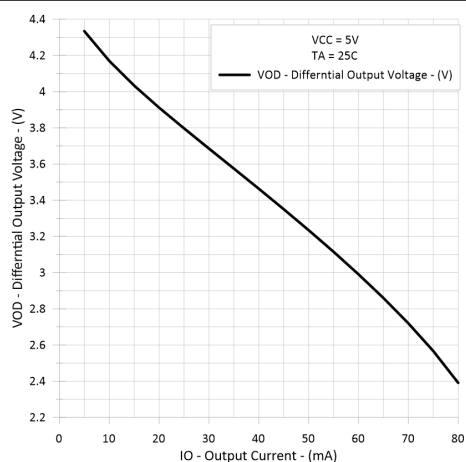


Figure 5-3. Driver Differential Output Voltage vs Output Current

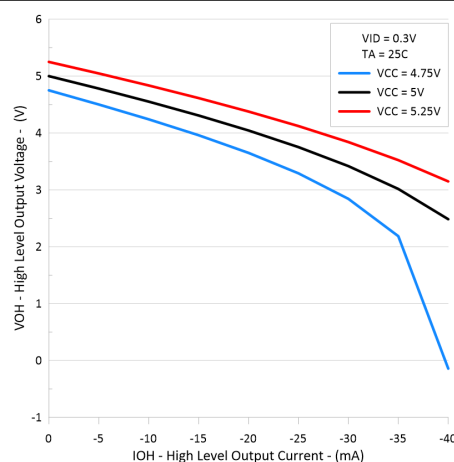


Figure 5-4. Receiver High-Level Output Voltage vs High-Level Output Current

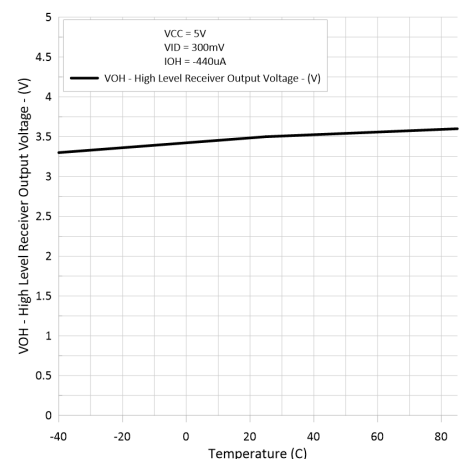


Figure 5-5. Receiver High-Level Output Voltage vs Free-Air Temperature

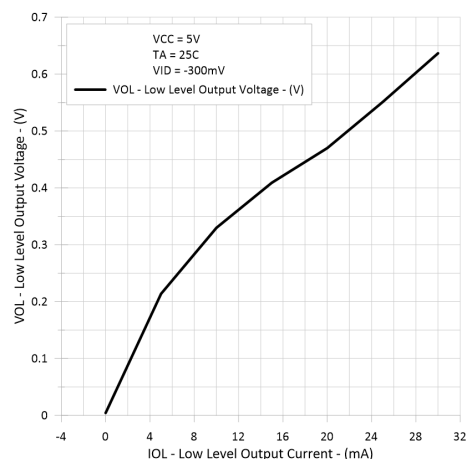


Figure 5-6. Receiver Low-Level Output Voltage vs Low-Level Output Current

5.11 Typical Characteristics (continued)

Operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied.

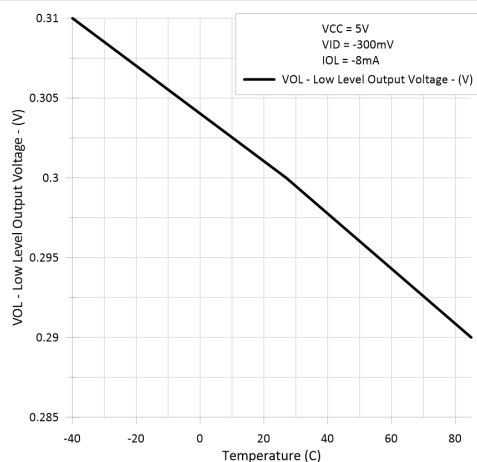


Figure 5-7. Receiver Low-Level Output Voltage vs Free-Air Temperature

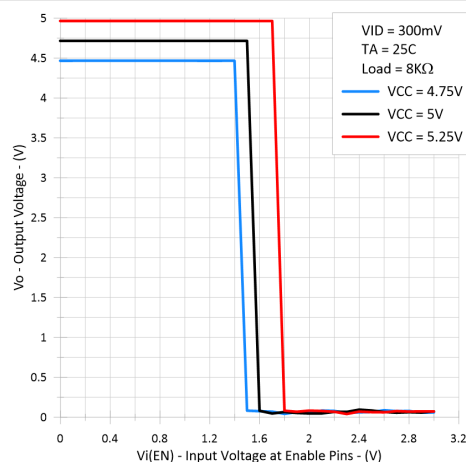


Figure 5-8. Receiver Output Voltage vs Enable Voltage

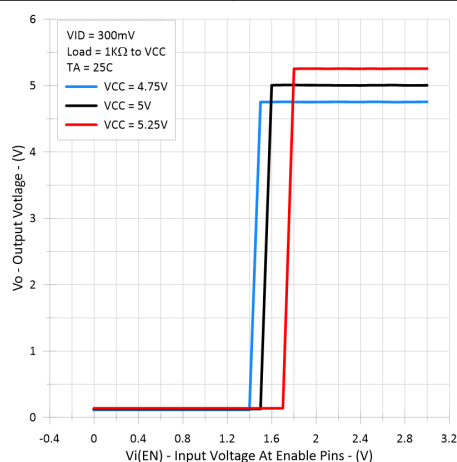


Figure 5-9. Receiver Output Voltage vs Enable Voltage

6 Parameter Measurement Information

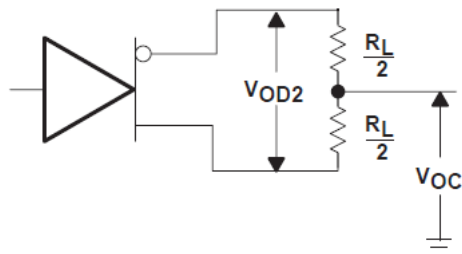


Figure 6-1. Driver V_{OD2} and V_{OC}

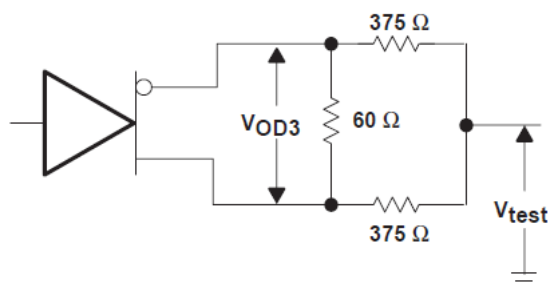
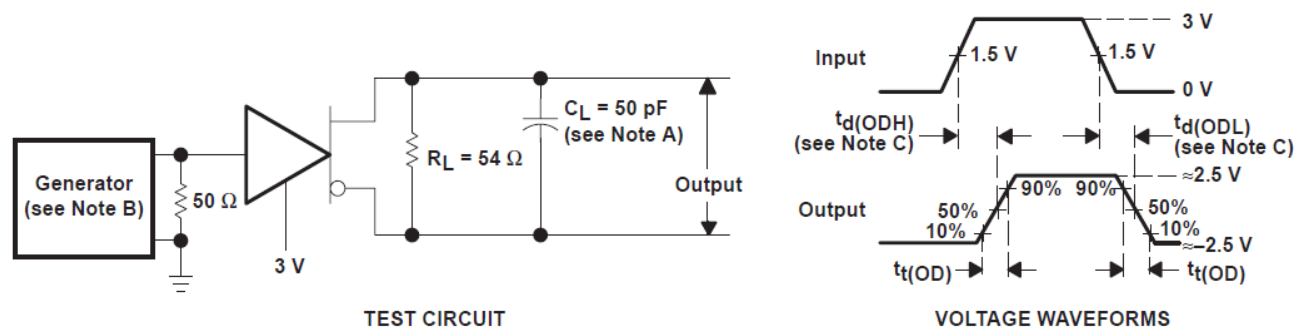
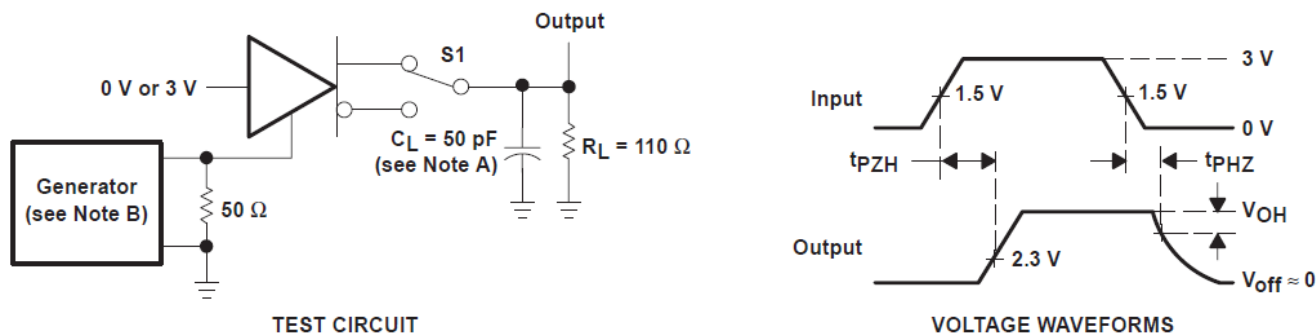


Figure 6-2. Driver V_{OD3}



- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

Figure 6-3. Driver Test Circuit and Voltage Waveforms



- A. C_L includes probe and jig capacitance.

- B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

Figure 6-4. Driver Test Circuit and Voltage Waveforms

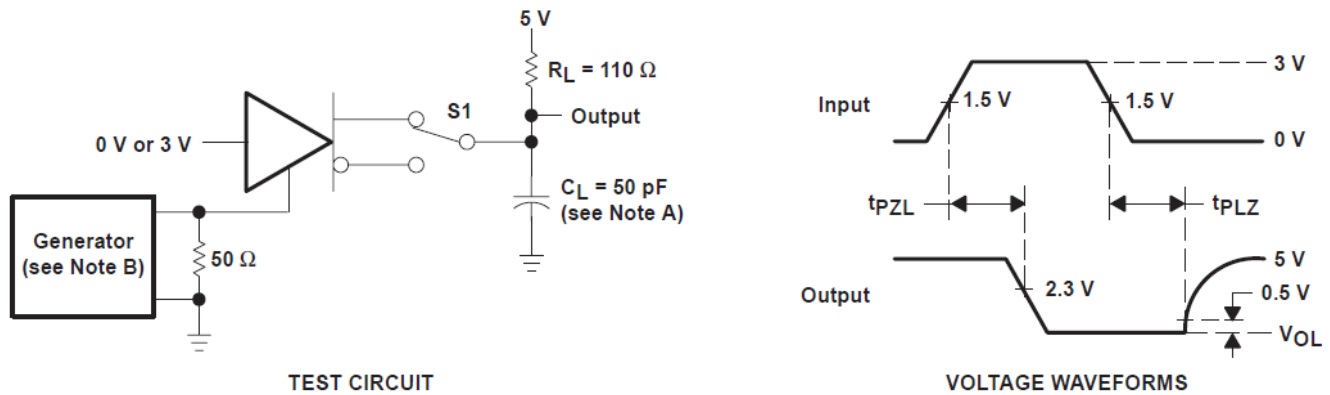


Figure 6-5. Driver Test Circuit and Voltage Waveforms

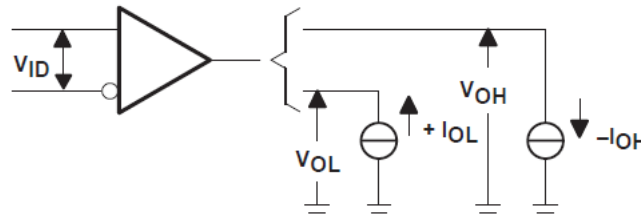
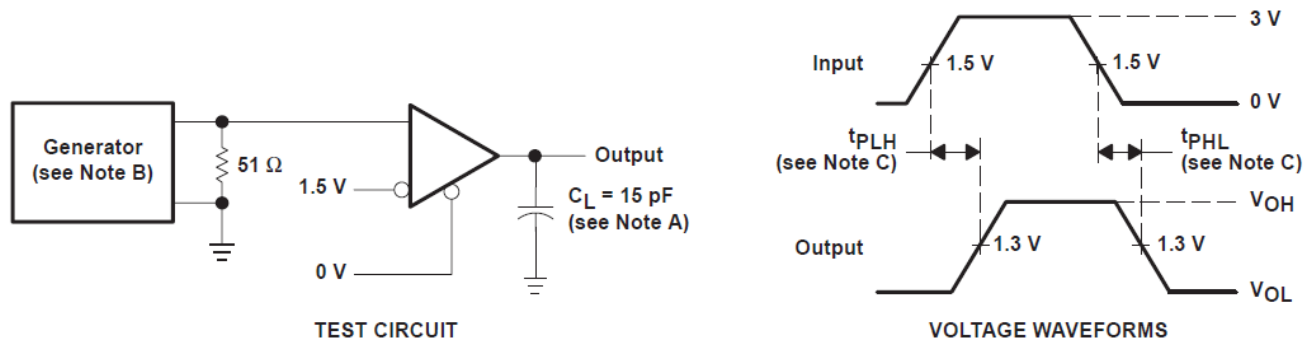
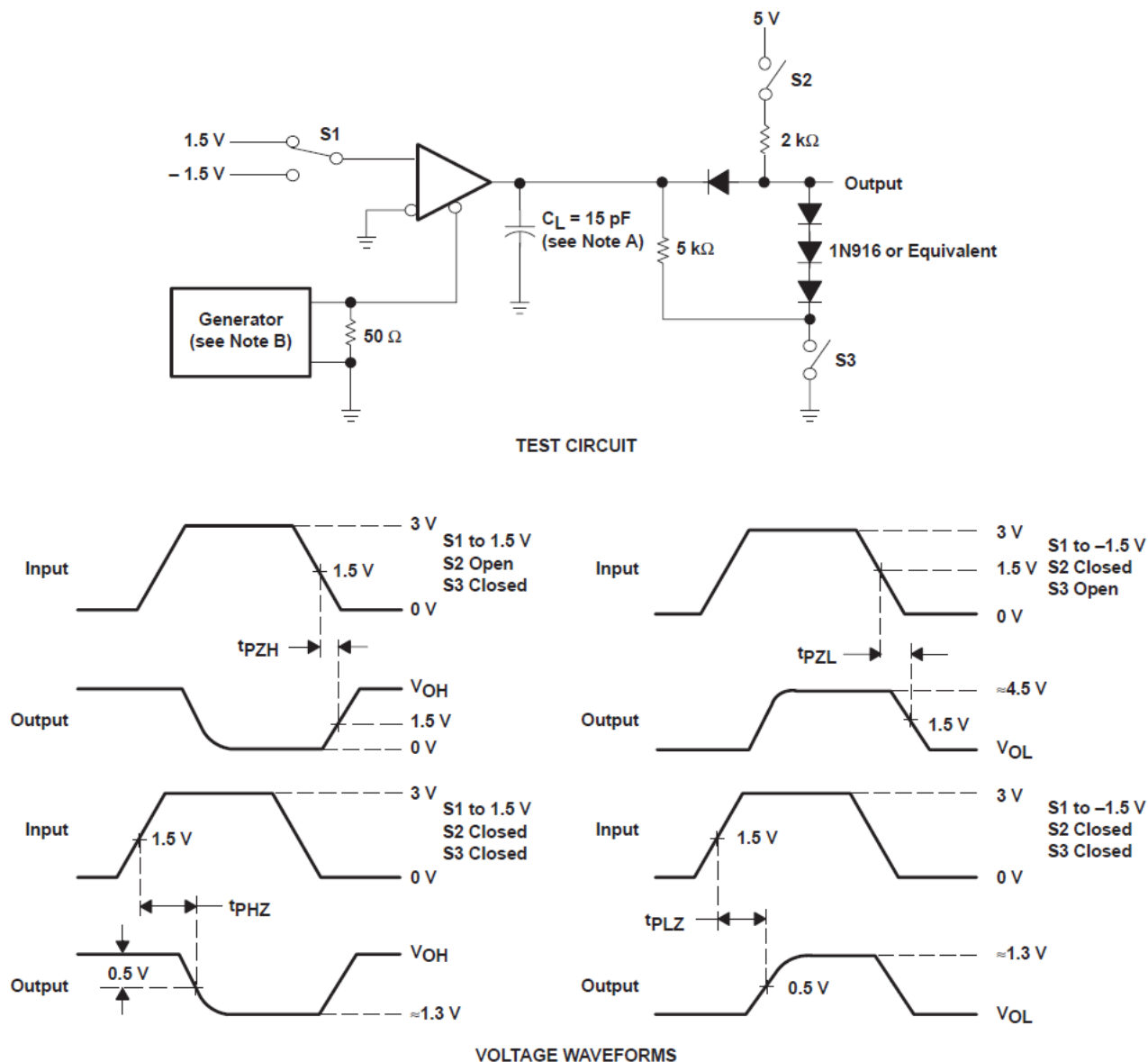


Figure 6-6. Receiver V_{OH} and V_{OL} Test Circuit



- A. C_L includes probe and jig capacitance.
 B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
 C. $t_{pd} = t_{PLH}$ or t_{PHL} .

Figure 6-7. Receiver Test Circuit and Voltage Waveforms



- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

Figure 6-8. Receiver Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Functional Block Diagram

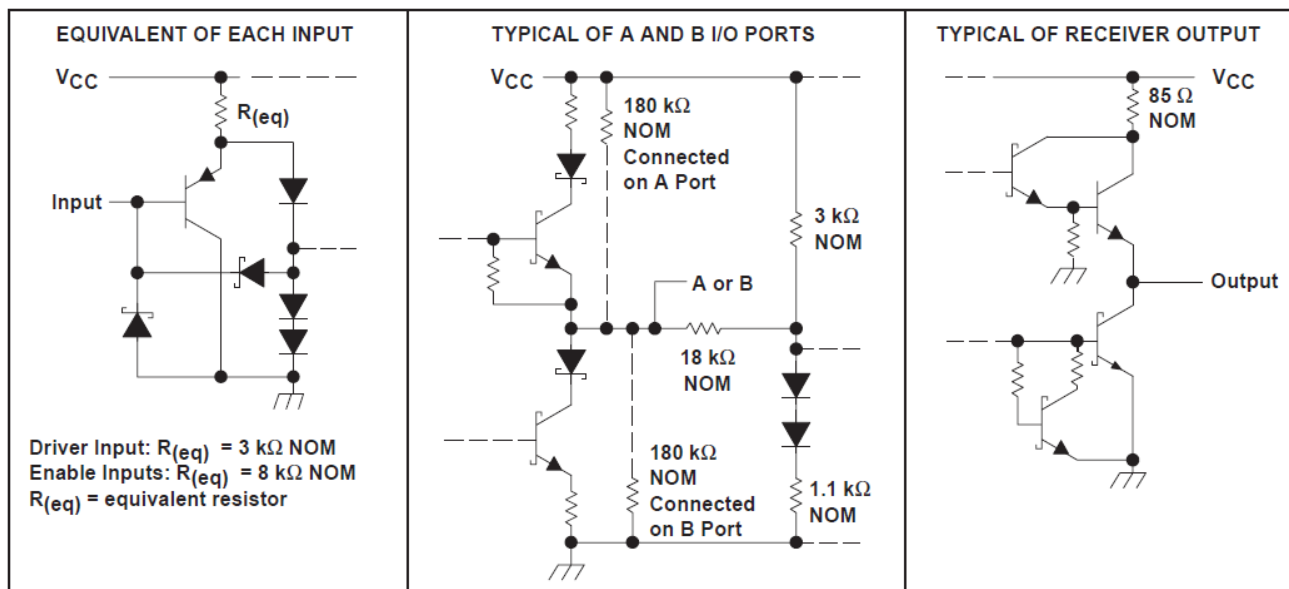


Figure 7-1. Schematic of Inputs and Outputs

7.2 Device Functional Modes

Function Tables

Table 7-1. Driver⁽¹⁾

INPUT D	ENABLE DE	OUTPUTS	
		A	B
H	H	H	L
L	H	L	H
X	L	Z	Z

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Table 7-2. Receiver⁽¹⁾

DIFFERENTIAL INPUTS A-B	ENABLE RE	OUTPUT R
$V_{ID} \geq 0.2 \text{ V}$	L	H
$-0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$	L	?
$V_{ID} \leq -0.2 \text{ V}$	L	L
X	H	Z
Inputs open	L	H

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

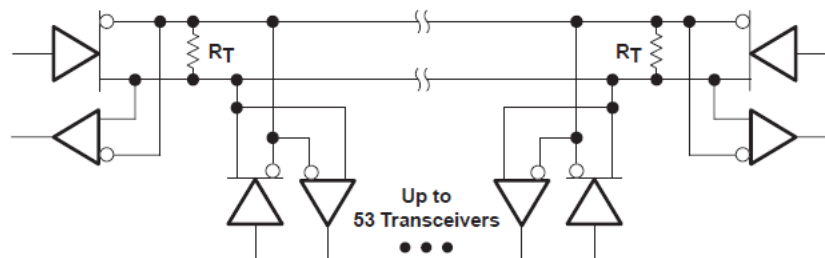
8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.2 Typical Application



- A. The line should terminate at both ends in its characteristic impedance ($R_T = Z_0$). Stub lengths off the main line should be kept as short as possible.

Figure 8-1. Typical Application Circuit

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.1.1 Related Documentation

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65ALS176DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65A176
SN65ALS176DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65A176
SN65ALS176DR1G4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65A176
SN65ALS176DR1G4.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65A176
SN75ALS176AD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7A176A
SN75ALS176AD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7A176A
SN75ALS176ADR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7A176A
SN75ALS176ADR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7A176A
SN75ALS176ADRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7A176A
SN75ALS176AP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176A
SN75ALS176AP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176A
SN75ALS176BD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	7A176B
SN75ALS176BDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	(75A176, 7A176B)
SN75ALS176BDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	(75A176, 7A176B)
SN75ALS176BP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176B
SN75ALS176BP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176B
SN75ALS176D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	75A176
SN75ALS176P	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176
SN75ALS176P.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176
SN75ALS176PE4	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	75ALS176

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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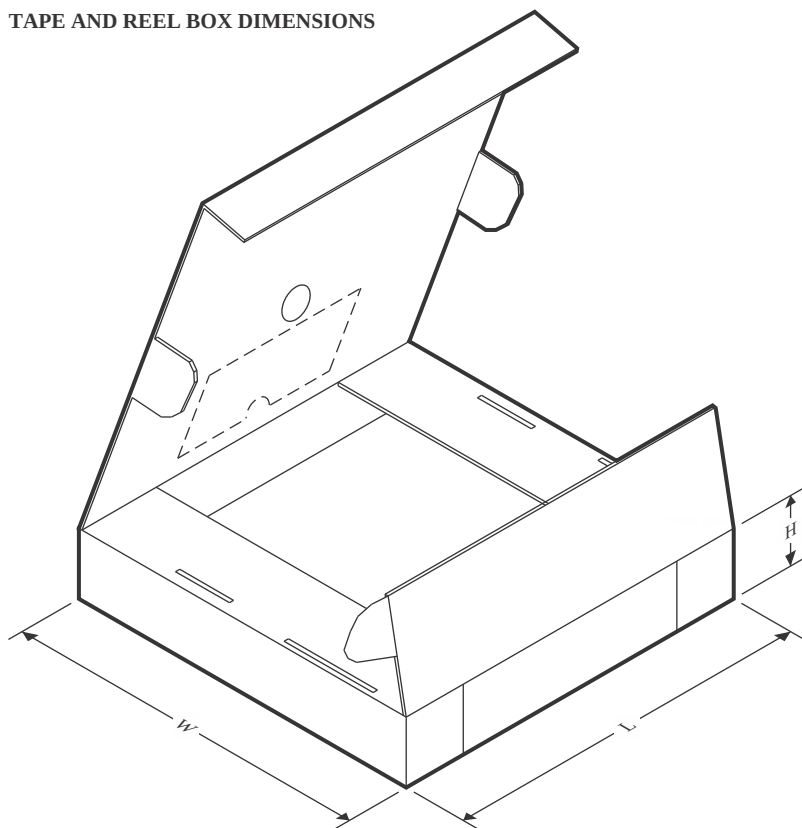
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65ALS176DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65ALS176DR1G4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75ALS176ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75ALS176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

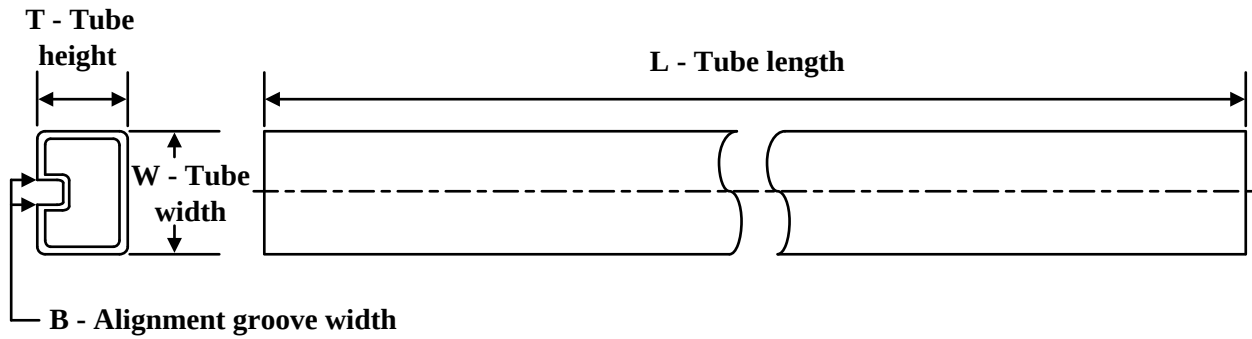
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65ALS176DR	SOIC	D	8	2500	340.5	336.1	25.0
SN65ALS176DR1G4	SOIC	D	8	2500	353.0	353.0	32.0
SN75ALS176ADR	SOIC	D	8	2500	353.0	353.0	32.0
SN75ALS176BDR	SOIC	D	8	2500	340.5	336.1	25.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN75ALS176AD	D	SOIC	8	75	507	8	3940	4.32
SN75ALS176AD.A	D	SOIC	8	75	507	8	3940	4.32
SN75ALS176AP	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176AP.A	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176BP	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176BP.A	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176P	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176P.A	P	PDIP	8	50	506	13.97	11230	4.32
SN75ALS176PE4	P	PDIP	8	50	506	13.97	11230	4.32



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



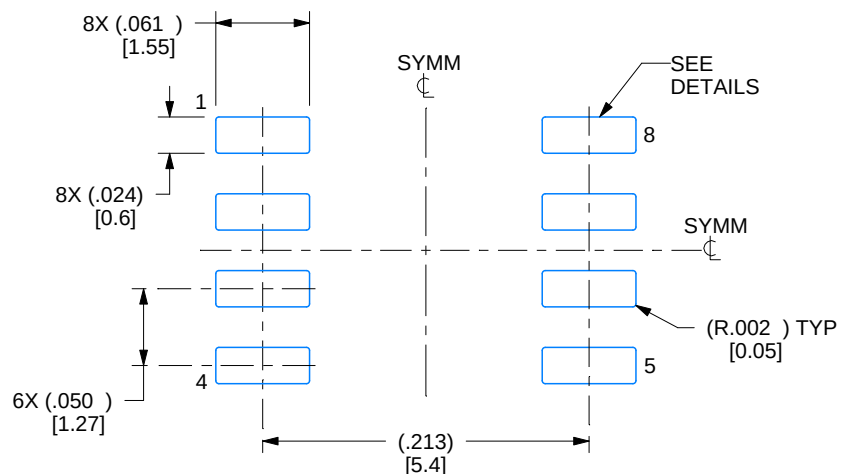
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

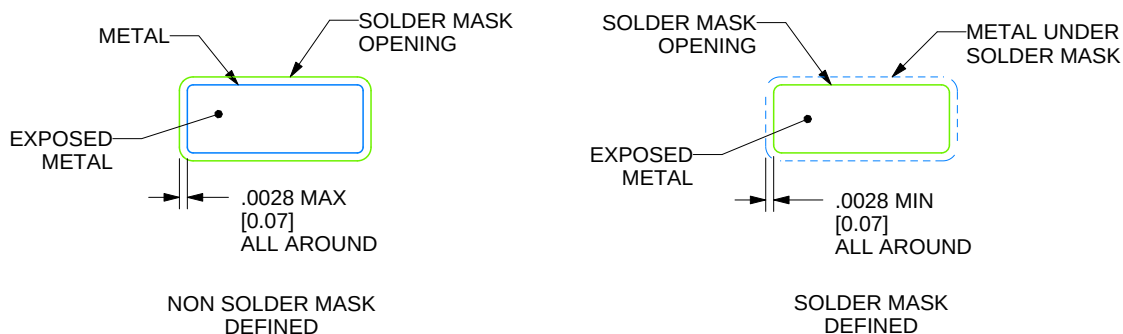
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

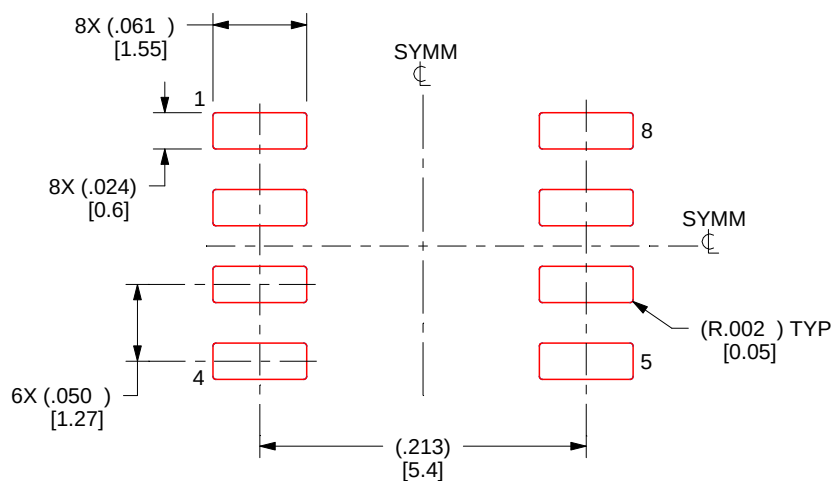
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

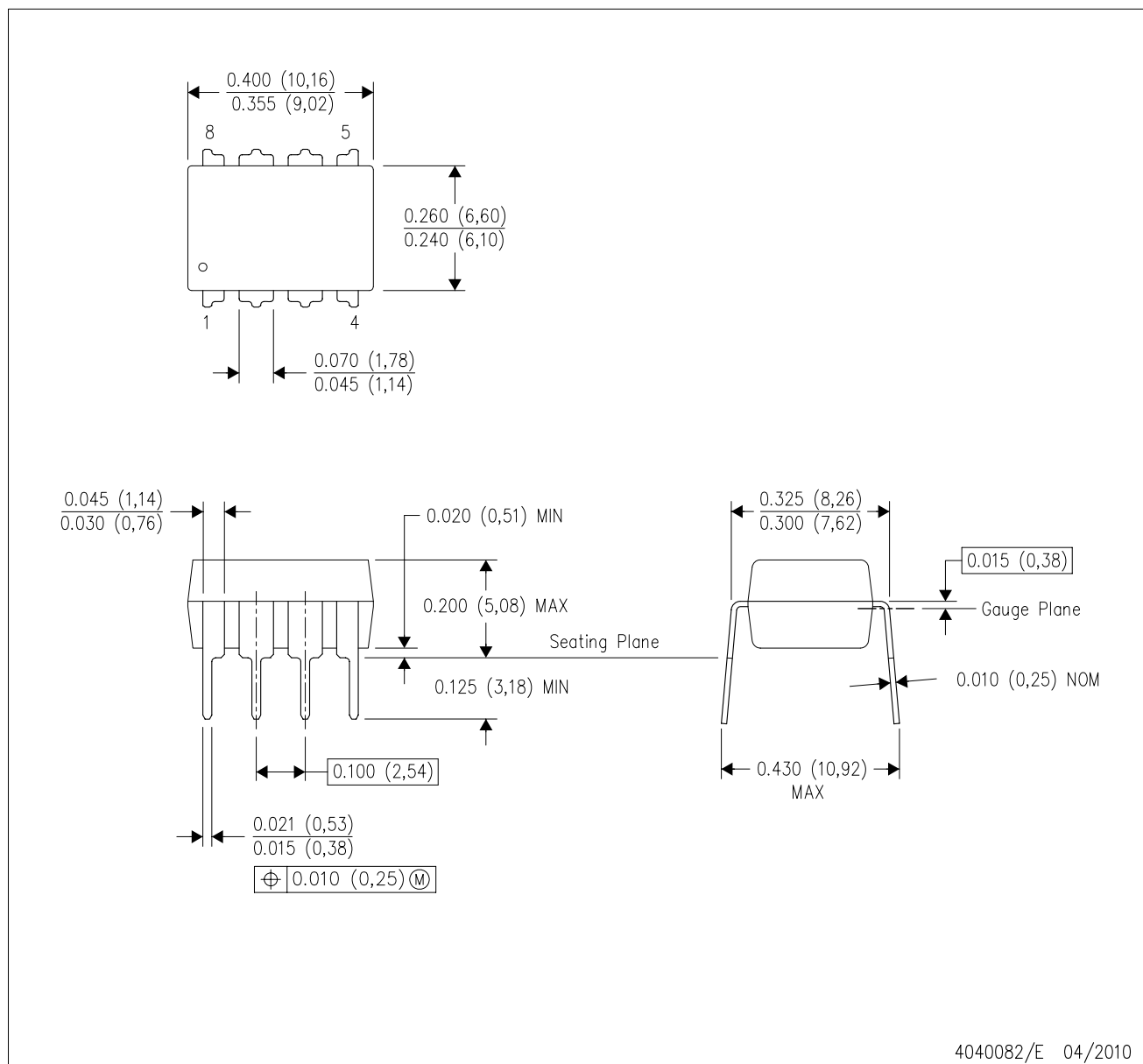
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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